## NSN 5961-00-883-6992

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View Online at https://aerobasegroup.com/nsn/5961-00-883-6992 **Inclosure Material:** Metal **Overall Length:** 0.328 inches Overall Diameter: 0.750 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 140.0 collector to base voltage/static/emitter open and 120.0 breakdown voltage, collector to emitter, sustained and 140.0 collector to emitter voltage, dc with specified circuit between base and emitter and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 120.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 98230-ono96882 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:** 

No

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**Demilitarization:**